NSN 5961-01-008-6030

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-008-6030 **Inclosure Material:** Metal **Overall Length:** 1.200 inches **Overall Diameter:** 1.150 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud and threaded hole **Features Provided:** Hermetically sealed case **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 900.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 threaded hole and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0